

# isc N-Channel MOSFET Transistor

## 2SK1384

#### **DESCRIPTION**

- Drain Current –I<sub>D</sub>=5A@ T<sub>C</sub>=25 ℃
- · Drain Source Voltage-
  - : V<sub>DSS</sub>=800V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



### **APPLICATIONS**

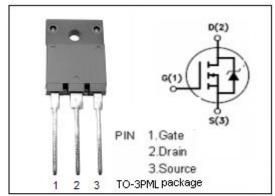
· high voltage, high speed power switching

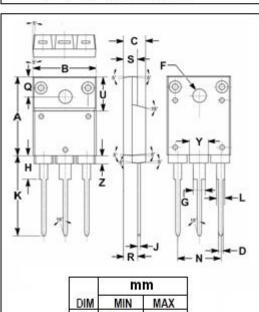


SYMBOL	ARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage (V <sub>GS</sub> =0)	800	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-continuous@ TC=25°C	5	Α
P <sub>tot</sub>	Total Dissipation@TC=25°C	80	W
T <sub>j</sub>	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}\!\mathbb{C}$



SYMBOL	PARAMETER	MAX	UNIT
Rth j-c	Thermal Resistance,Junction to Case	1.56	°C/W
R <sub>th j-a</sub>	Thermal Resistance,Junction to Ambient	30	°C/W





1-1-01-01		
DIM	MIN	MAX
Α	19.90	20.10
В	15.90	16.10
С	5.50	5.70
D	0.90	1.10
F	3.30	3.50
G	2.90	3.10
Н	5.90	6.10
J	0.595	0.605
K	22.30	22.50
L	1.90	2.10
N	10.80	11.00
0	4.90	5.10
R	3.75	3.95
S	3.20	3.40
U	9.90	10.10
Υ	4.70	4.90
Z	1.90	2.10

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#### • ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 10mA	800			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =1mA	2.1	3.0	4.0	V
R <sub>DS(on)</sub>	Drain-Source On-stage Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =2.5A		1.5	2.0	Ω
I <sub>GSS</sub>	Gate Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =800V; V <sub>GS</sub> = 0			500	uA
ton	Turn-on time	VGS=10V;ID=2.5A;		30	50	ns
toff	Turn-off time	RL=50 Ω		420	630	ns
V <sub>SD</sub>	Diode Forward Voltage	I <sub>F</sub> =5A; V <sub>GS</sub> =0		1.0	1.5	V



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